UNISONIC TECHNOLOGIES CO., LTD

UP1753

NPN SILICON TRANSISTOR

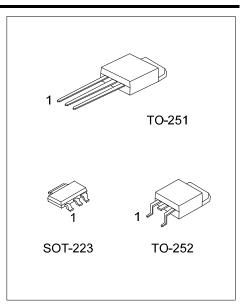
HIGH CURRENT LOW V_{CE(SAT)} **TRANSISTOR**

DESCRIPTION

The UTC UP1753 is specially designed to have high current and low $V_{\text{CE}(\text{SAT})}$ to suit for power amplifier application and power switching application.

FEATURES

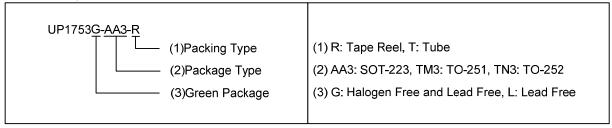
- *V_{CE(SAT)} typ. is below 300mV at 5A
- * Max continuous current 6 A
- * BV_{CEO} is 100V minimum



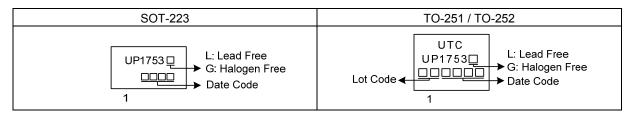
ORDERING INFORMATION

Ordering Number		Doolsone	Pin Assignment			Deakins	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UP1753L-AA3-R	UP1753G-AA3-R	SOT-223	В	С	E	Tape Reel	
UP1753L-TM3-T	UP1753G-TM3-T	TO-251	В	С	Е	Tube	
UP1753L-TN3-T	UP1753G-TN3-T	TO-252	В	С	Е	Tube	
UP1753L-TN3-R	UP1753G- TN3-R	TO-252	В	С	Е	Tape Reel	

E: Emitter Note: Pin Assignment: B: Base C: Collector



MARKING



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V_{CBO}	200	V	
Collector-Emitter Voltage		V_{CEO}	100	V	
Emitter-Base Voltage		V_{EBO}	6	V	
Peak Pulse Current		I _{CM}	10	Α	
Continuous Collector Current		Ic	6	Α	
Collector Power Dissipation		SOT-223	- P _C	0.8	W
	T _A =25°C	TO-251 TO-252		1	W
	T 05°0	SOT-223		2	W
	T _C =25°C (Note)	TO-251 TO-252		25	W
Junction Temperature		TJ	+150	°C	
Storage Temperature		T _{STG}	-55 ~ + 150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

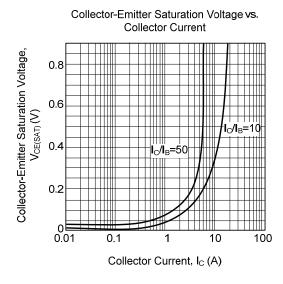
■ **ELECTRICAL CHARACTERISTICS** (T_A= 25°C, unless otherwise specified)

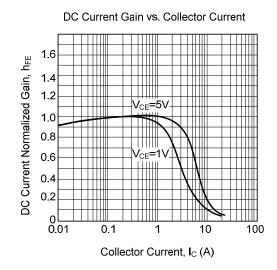
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_CBO	I _C =100μA	200	300		V
Collector-Emitter Breakdown Voltage	BV_CEO	I _C =10mA (Note1)	100	120		V
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =100μA	6	8		V
Collector Cut-Off Current	I_{CBO}	V _{CB} =150V			10	nA
Collector Cut-Off Current	I _{CER}	V _{CE} =150V, R≤1KΩ			10	nA
Emitter Cut-Off Current	I _{EBO}	V _{EB} =6V			10	nA
Collector-Emitter Saturation Voltage	$V_{\text{CE}(\text{SAT})}$	I _C =0.1A, I _B =5mA (Note1)			50	mV
		I _C =2A, I _B =100mA (Note1)			150	mV
		I _C =5A, I _B =500mA (Note1)			330	mV
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	I _C =5A, I _B =500mA (Note1)			1250	mV
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	I _C =5A, V _{CE} =2V (Note1)			1100	mV
Static Forward Current Transfer Ratio	h _{FE}	I _C =10mA, V _{CE} =2V	100	200		
		I _C =2A, V _{CE} =2V (Note1)	100	200	300	
		I _C =4A, V _{CE} =2V (Note1)	50	100		
		I _C =10A, V _{CE} =2V (Note1)	20			
Output Capacitance	C_OB	V _{CB} =10V, f=1MHz		38		pF
Rise Time	t_R			60		ns
Storage Time	ts	I _C ≤-500mA, I _{B1} =I _{B2} =10mA		2000		ns
Fall Time	t_{F}			70		ns

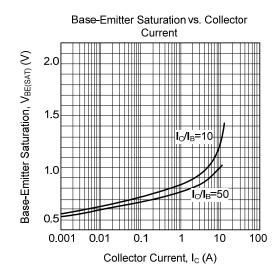
Note: 1.Measured under pulsed conditions. Pulse width=300 μ s. Duty cycle \leq 2%,

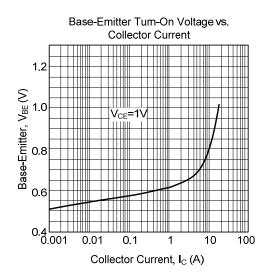
^{2.} Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

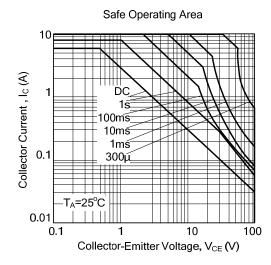
■ TYPICAL CHARACTERISTICS











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